NSN 5961-00-262-0317

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-262-0317 **Inclosure Material:** Glass and metal **Overall Length:** Between 0.800 inches and 0.840 inches Overall Diameter: Between 0.220 inches and 0.240 inches **Mounting Method:** Press fit **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon **Maximum Operating Tempurature Per Measurement Point:** 70.0 degrees celsius ambient air **Special Features:** S-band detector **Precious Material And Location:** Body surface gold **Test Data Document:** 81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Terminal Type And Quantity:** 1 pin and 1 case **Specification Data:** 81349-mil-s-19500/237 government specification Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: